## 13-Defects, Microstructures and Textures

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PS-13.03.06 A STUDY OF THE EFFECT OF THE ORIENTATION OF MICROCRYSTALS ON THE PROPERTIES OF IRON-BASED AMORPHOUS ALLOY Fe<sub>78</sub>Si<sub>8</sub>B<sub>13</sub>. By Sun Shi-Quan\*, Wang Cheng-Zhong and Shi Song-Yue, Shanghai Iron and Steel Research Institute, 1001 Taihe Road, Wusong, Shanghai 200940, P. R. China.

It is known that the properties of amorphous alloys are closely related to their structural change during crystallization. The influence of crystallite size and crystallinity on properties (Sun Shi-Quan et al., PHYSICS, 1989, 19,9,561), and the influence of the annealing temperature on crystallinity (Sun Shi-Quan et al., Journal of Physical Testing and Chemical Analysis, Part A. Physical Testing, 1988, 24, 2, 9) have already been investigated. In this paper, the results of the effect of crystalline orientation on the properties of the iron-based amorphous alloy, Fe78Si9B13, studied using X-ray diffraction associated with magnetic and mechanical testing, are reported. The tested alloys, A and B, were prepared with different processes but with the same constituents and the same treatment. The asquenched ribbons were annealed at 450°C for 0.5 hour in a furnace filled with argon. Then, the pole figures, the magnetic properties (B<sub>1</sub>, B<sub>10</sub>, B<sub>30</sub>, Br, Hc) and the mechanical properties were measured for specimens A and B by means of X-ray diffraction, magnetic and mechanical testing. The results showed that: (a) the texture of specimen A is similar to (200) [HKL], and specimen B has an approximate cubic texture. The orientation of the microcrystals is parallel to the preferred magnetic direction for specimen B but not for specimen A. The measured magnetic properties of specimen B are better than those of A; (b) the pole figures obtained by X-ray diffraction are, for both specimens, slightly asymmetric, due to the deformation of the microcrystals during crystallization. The measured mechanical properties are also characterized by an anisotropy, i. e., the longitudinal bending forces are different from the transversal ones. To sum up, the experimental results obtained by X-ray diffraction are in good agreement with those obtained by magnetic and mechanical testing.

PS-13.03.07 INFLUENCES OF ELASTIC STRAIN AT OXIDE MASK EDGES ON THE DISTRIBUTION OF B IONS IMPLANTED IN SILICON CRYSTALS. By A. Yu. Nikulin\*, O. Sakata and H. Hashizume, Tokyo Institute of Technology, Nagatsuta, Midori, Yokohama 227, Japan.

A method of reconstructing two-dimensional elastic deformation fields in near-surface layers was developed for the case of distortions which are periodic in one direction (Goureev, Nikulin & Petrashen, phys. stat. sol.(a) 130, 2 (1992). The method is based on the application of the solution of one dimensional inverse problem to the Fourier components of the deformation profile and analyzes, interference patterns observed in triple-crystal X-ray rocking curves. It was applied to a silicon crystal with periodic surface SiOz strips (10  $\mu\rm m$  period) and a silicon crystal implanted with Ne¹ ions (300 keV,  $\sim 10^{14}\,\rm cm^{-2})$  through a periodic mask which was removed after the implantation (Aristov,

Goureev, Nikulin et al., Semicond. Sci. Tech. 7, 1109 (1992)). In the latter application the obtained lattice deformation profile is in good agreement with the known character of the implanted ions. For instance, the deformation depth range (0.45  $\mu \, \mathrm{m})$  and the average width of the profile maximum (0.1  $\mu \, \mathrm{m})$  were very close to the results of Monte-Carlo calculations.

It is interesting to see if this method allows to study the influences of elastic strain at the edges of oxide masks on the distribution of implanted ions. Experiments were carried out on Si(111) crystals implanted with B+ (100-300 keV,  $10^{15}\,\mathrm{cm}^{-2}$ ) through a 0.5  $\mu\,\mathrm{m}$ -thick SiO2 mask having a 5.83  $\mu\,\mathrm{m}$  periodicity. A triple-crystal diffractometer was used with synchrotron X-rays for the 111 and 004 reflections. It was attempted to obtain a unique solution of the inverse problem from data collected using two different X-ray wavelengths. Effects of anisotropic strain at the mask edges on the ion distribution will also be reported.

PS-13.03.08 CHARACTERIZATION OF QUANTUM WELL WIRES AND SURFACES GRATINGS BY X-RAY DIFFRACTION RECIPROCAL SPACE MAPPING. By G.T. Baumbach\*(a), M. Gailhanou(b), U. Marti(b), P. Silva(b), M. Bessiere(c), F.K. Reinhart(b), M. Ilegems(b), (a) Institut Laue-Langevin, BP 156X, F38 042 Grenoble Cedex (France) (b) Institut de Micro- et Optoélectronique, Ecole Polytechnique Fédérale de Lausanne CH1015 Lausanne (Switzerland) (c) LURE, Bat.209d, Université Paris Sud, F91 405 Orsay Cedex (France)

One tendency in the present material research is the increasing ability to structure solids in one, two or three dimensions. Using semiconductor systems, quantum well wires (QWW) and quantum well dots (QWD) hold a great potential for the basic physics of semiconductors as well as for the improvement of integrated optical devices. One approach consists of post-growth patterning of quantum well materials, a second one of its fabrication on patterned non-planar substrates (PS). The aim of our studies was to develop the method of X-ray diffraction

The aim of our studies was to develop the method of X-ray diffraction as a powerful nondestructive technique for the structural characterization of periodic natterned substrates and OWW

of periodic patterned substrates and QWW. QWW and PS represent artificial superlattices. The PS have an one-dimensional lateral superstructure forming a surface grating with periods between 0.2 and 1  $\mu m$ . The QWW are epitaxial multilayered surface gratings and show a two-dimensional superperiodicity. By applying triple crystal diffractometry longitudinal (Qz) truncation rods (TR) near the Bragg positions of the modulated crystal-lattice have been measured directly (see fig.1) (1). The transversal (Qx) positions of the

Realizing transversal  $(Q_X)$  scans, satellites occur around the substrate Bragg-peak. The angular space between neighbouring satellites is inverse to the grating period. A longitudinal scan through the substrate Bragg position shows thickness oscillations related with the grating depth. An intensity cross pattern is formed by the longitudinal truncation rods of the transversal satellites in fig.1, centered on the substrate reciprocal lattice point. It provides evidence of a non square shaped profile of the grating, found to be trapezoidal in this example. The grating acts simultaneously as a reflection and a transmission grating. Umweganregung between the (transmission)-grating and the dynamical diffracting substrate gives rise to additional sharp peaks in the maps, which cannot be explained by normal kinematical theory. For the quantitative interpretation a semi-dynamical treatment was developed.

ped.
In QWW's the Qz truncation rods obtain additional longitudinal satellites, representing the superperiodicity in growth direction. Both longitudinal satellites and transversal satellites would not be separable in a smooth way by applying only double crystal diffractometry. Reciprocal space mappings allow the characterization of the perpendicular profile of the QWW-stripes as well as the surface profile of the lateral grating. That will be demonstrated by the example of stepwise etched epitaxial multilayered surface gratings based on GaInAs/InP and AlAs/GaAs.